

# HD74LS243

Quadruple Bus Transceivers (with three-state outputs)

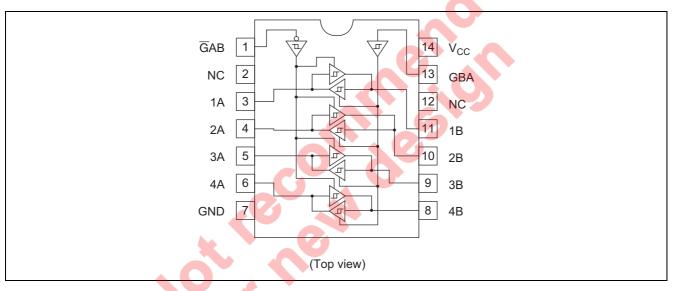
REJ03D0462-0300 Rev.3.00 Jul.15.2005

### Features

• Ordering Information

Part Name	Package Type	Package Code (Previous Code)	Package Abbreviation	Taping Abbreviation (Quantity)
HD74LS243FPEL	SOP-14 pin (JEITA)	PRSP0014DF-B (FP-14DAV)	FP	EL (2,000 pcs/reel)

## **Pin Arrangement**



### **Function Table**

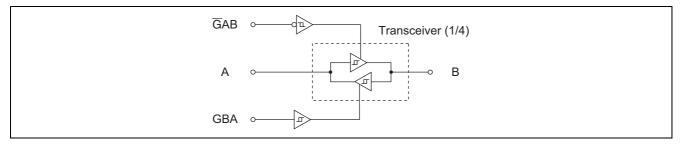
Con	trol input	Data port status		
GAB	GBA	A	В	
Н	Н	Output	Input	
L	Н		k	
Н	L	Isolated	Isolated	
L	L	Input Output		

Notes: 1. H; high level, L; low level

2. \*; Possibly destructive oscillation may occur if the transceivers are enabled in both directions at once.



#### **Block Diagram**



### **Absolute Maximum Ratings**

Item		Symbol	Ratings	Unit
Supply voltage		V <sub>CC</sub>	7	V
	GAB, GBA	V <sub>IN</sub>	7	V
Input voltage	А, В	V <sub>IN</sub>	5.5	V
Power dissipation		P <sub>T</sub>	400	mW
Storage temperature		Tstg	-65 to +150	٥C

Note: Voltage value, unless otherwise noted, are with respect to network ground terminal.

# **Recommended Operating Conditions**

ltem	Symbol	Min	Тур	Max	Unit
Supply voltage	V <sub>CC</sub>	4.75	5.00	5.25	V
Output current	I <sub>OH</sub>			-15	mA
Output current	IOL	$\rightarrow$		24	mA
Operating temperature	Topr	-20	25	75	°C
. (		C ·			



### **Electrical Characteristics**

 $(Ta = -20 \text{ to } +75 \ ^{\circ}\text{C})$ 

Item		Symbol	min.	typ.*	max.	Unit	C	Condition	
Input voltage		V <sub>IH</sub>	2.0	_	_	V			
		V <sub>IL</sub>		—	0.8	V			
Hysteresis		$V_T^+ - V_T^-$	0.2	0.4	_	V	V <sub>CC</sub> = 4.75 V		
		V <sub>OH</sub>	2.4	_		V			$V_{CC} = 4.75 V$ ,
Output voltage			2	—	_	v			V <sub>IH</sub> = 2 V
	Jilage	V <sub>OL</sub>	_	—	0.4	V	$I_{OL} = 12 \text{ mA}$	$V_{CC} = 4.7$	75 V, V <sub>IH</sub> = 2 V,
		V OL	_	—	0.5	v	I <sub>OL</sub> = 24 mA	V <sub>IL</sub> = 0.8	V
Off-state	output current	I <sub>OZH</sub>	_	—	40	μA	$V_{O} = 2.7 V$		25 V, V <sub>IH</sub> = 2 V,
On-state	ouiput current	I <sub>OZL</sub>	_	—	-200	μA	$V_{O} = 0.4 V$	$V_{IL} = 0.8 V$	
		Іін	_	—	20	μA	$V_{CC} = 5.25 \text{ V}, \text{ V}_{I} = 2.7 \text{ V}$		
	A Input			_	-0.2		$V_{CC} = 5.25 \text{ V}, \text{ V}_{I} = 0.4 \text{ V},$		
	Апри	I <sub>IL</sub>					GAB or GBA at GND		
Input	B Input		_	_	-0.2	mA	$V_{CC} = 5.25 \text{ V}, \text{ V}_{I} =$		
current						-	GAB or GBA at 4.		
	GAB or GBA		—	—	-0.2		V <sub>CC</sub> = 5.25 V, V <sub>I</sub> =		
	A or B	- Iı	—	—	0.1	mA	$V_{CC} = 5.25 \text{ V}, \text{ V}_{I} = 5.5 \text{ V}$		
	GAB or GBA	-1	_	—	0.1		$V_{CC} = 5.25 \text{ V}, \text{ V}_{I} = 7 \text{ V}$		
Short-circuit output		los	-40	_	-225	mA	V <sub>cc</sub> = 5.25 V		
current		.00							
Supply current**		Іссн	_	22	38				
		ICCL	_	29	50	mA	$V_{CC} = 5.25 V$		
		Iccz	—	32	54				
Input clamp voltage		VIK	_	_	-1.5	V	V <sub>CC</sub> = 4.75 V, I <sub>IN</sub> =	= –18 mA	

Notes: \*  $V_{CC} = 5 V$ , Ta = 25°C

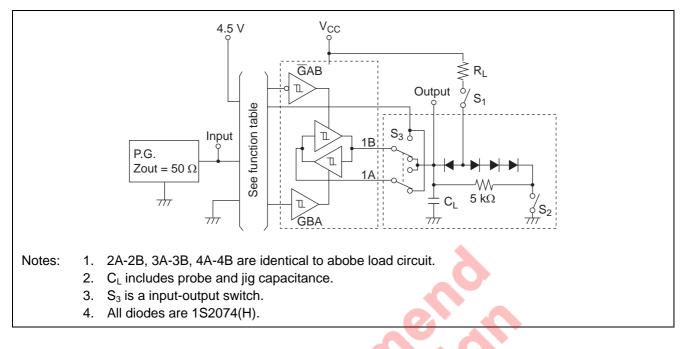
\*\* With all outputs open, I<sub>CC</sub> is measured with transceivers enabled in one direction only, or with all transceivers disabled.

# Switching Characteristics

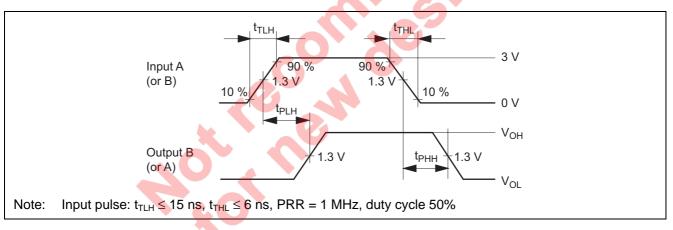
			$(V_{CC} = 5 V, Ta = 25^{\circ}C)$				
Item	Symbol	min.	typ.	max.	Unit	Condition	
Propagation delay time	<b>t</b> PLH		12	18			
	t <sub>PHL</sub>		12	18		$C_L$ = 45 pF, $R_L$ = 667 $\Omega$	
Output enable time	t <sub>ZL</sub>	_	20	30	ns		
	t <sub>ZH</sub>	_	15	23	115		
Output disable time	t <sub>LZ</sub>	—	15	25		$C_{L} = 5 \text{ pF}, R_{L} = 667 \Omega$	
	t <sub>HZ</sub>	—	10	18		$C_{L} = 5 \text{ pr},  \text{R}_{L} = 007   \text{22}$	

# **Testing Method**

### **Test Circuit**



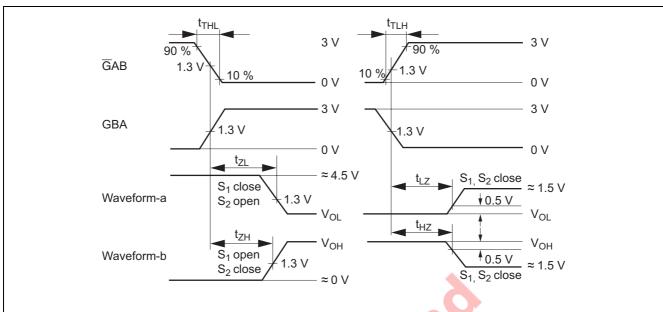
Waveforms 1





#### HD74LS243

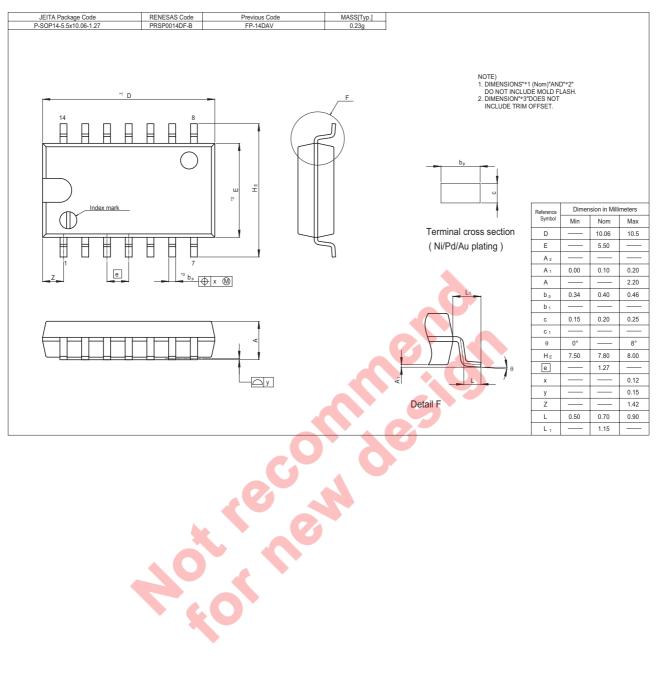
#### Waveforms 2



- Notes: 1. Input pulse:  $t_{TLH} \le 15$  ns,  $t_{THL} \le 6$  ns, PRR = 1 MHz, duty cycle 50%
  - 2. Waveform a is an output by internal conditions like "L" except for the case where an output is disabled by output control.
  - 3. Waveform b is an output by internal conditions like "H" except for the case where an output is disabled by output control.

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## **Package Dimensions**





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